

## 1. Features

- Typical 1dB bandwidth of 18.9 MHz
- High attenuation
- Single Ended Operation
- Dual In-line Package (DIP)

**RoHS Compliant**

Tested by SGS Testing Korea

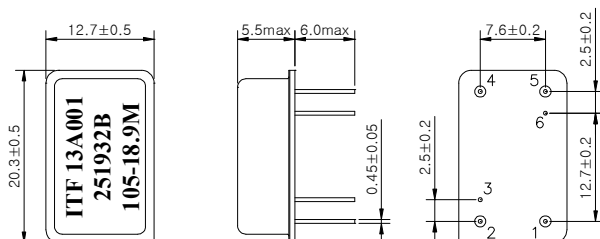
## 2. Electrical Specifications

Source and Load Impedance = 50Ω

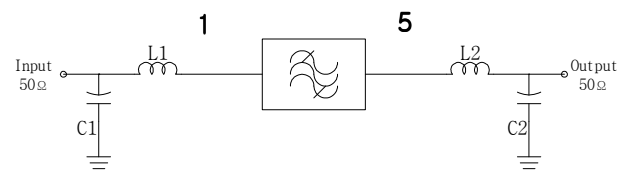
Room Temperature : +25°C		Minimum	Typical	Maximum
Center Frequency (fo)	MHz	104.88	105.0	105.12
Insertion Loss	dB	-	23.5	25.0
1dB Bandwidth	MHz	18.80	18.92	-
3dB Bandwidth	MHz	-	19.21	-
45dB Bandwidth	MHz	-	20.51	20.60
Amplitude Ripple (Fo±9.22MHz)	dB	-	0.5	1.0
Group Delay Variation (Fo±9.22MHz)	nsec	-	40	100
Absolute Delay	usec	-	2.24	2.28
Ultimate Rejection	dB	50	55	-
Temperature Coefficient of Frequency	ppm/°C	-	-72	-
Substrate Material	-		128-LN	

\* Input POWER : 10dBm

### D2012 Package Dimension



### Matching Schematic



L1 = 82nH, L2 = 56nH, C1 = 39pF, C2 = 18pF

Dimensions shown are nominal in millimeters

Base : Fe(SPCC), Au plating over Ni plated  
Cap : Cu & Cr Alloy, Ni Plated  
Termination : Kovar, Au Plated

### Pin Configuration

	1	Ground	2,4
Input	1	Ground	2,4
Output	5	Others	Ground

**3. Typical Performance ( at +25°C )**

